

## 4A, 600V - 1000V Glass Passivated Bridge Rectifier

#### FEATURES

**TAIWAN** 

• Glass passivated junction

SEMICONDUCTOR

- Ideal for automated placement
- UL Recognized File # E-326854
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

#### APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- TV
- Monitor

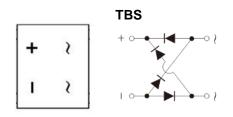
#### **MECHANICAL DATA**

- Case: TBS
- Molding compound meets UL 94V-0 flammability rating
- Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1 whisker test
- Polarity: As marked
- Weight: 0.22g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I <sub>F(AV)</sub>	4.0	А	
V <sub>RRM</sub>	600 - 1000	V	
I <sub>FSM</sub>	110	А	
T <sub>J MAX</sub>	150	°C	
Package	TBS		
Configuration	Quad		







ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER		SYMBOL	<b>твs</b> 406	TBS 408	ТВS 410	UNIT
Marking code on the device			TBS406	TBS408	TBS410	
Repetitive peak reverse voltage	Repetitive peak reverse voltage		600	800	1000	V
Reverse voltage, total rms value		V <sub>R(RMS)</sub>	420	560	700	V
Forward current		I <sub>F(AV)</sub>	4.0		А	
Surge peak forward current $8.3 \text{ ms at } T_A = 25^{\circ}\text{C}$		110			А	
single half sine-wave superimposed on rated load	1.0 ms at T <sub>A</sub> = 25°C	I <sub>FSM</sub>	340		А	
l <sup>2</sup> t value (of a surge on-state current) at 8.3ms		l <sup>2</sup> t	50		A <sup>2</sup> s	
Junction temperature		TJ	-55 to +150		°C	
Storage temperature		T <sub>STG</sub>	-55 to +150		°C	



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-lead thermal resistance	R <sub>ejl</sub>	13	°C/W
Junction-to-ambient thermal resistance	R <sub>eja</sub>	50	°C/W
Junction-to-case thermal resistance	R <sub>eJC</sub>	13	°C/W

Thermal Performance Note: Units mounted on recommended PCB (16mm x 16mm Cu pad test board)

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage <sup>(1)</sup>	$I_F = 2.0 \text{ A}, T_J = 25^{\circ}\text{C}$		0.89	-	V
	$I_F = 4.0 \text{ A}, T_J = 25^{\circ}\text{C}$		0.95	1	V
	I <sub>F</sub> = 2.0 A, T <sub>J</sub> = 125°C	V <sub>F</sub>	0.78	-	V
	I <sub>F</sub> = 4.0 A, T <sub>J</sub> = 125°C		0.84	0.96	V
	T <sub>J</sub> = 25°C		-	2	μA
Reverse current @ rated $V_R^{(2)}$	T <sub>J</sub> = 125°C	– I <sub>R</sub>	-	200	μA
Junction capacitance	1 MHz, V <sub>R</sub> =4.0V	CJ	38	-	pF

#### Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

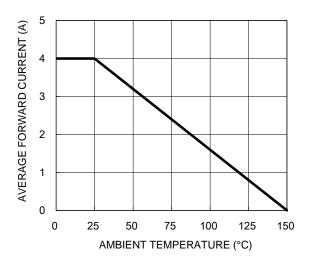
ORDERING INFORMATION			
ORDERING CODE	PACKAGE	PACKING	
TBS406 M1G	TBS	1,800 / 13" Plastic Reel	
TBS408 M1G	TBS	1,800 / 13" Plastic Reel	
TBS410 M1G	TBS	1,800 / 13" Plastic Reel	



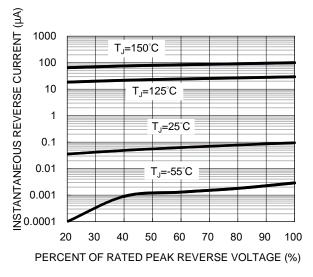
#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig.1 Forward Current Derating Curve



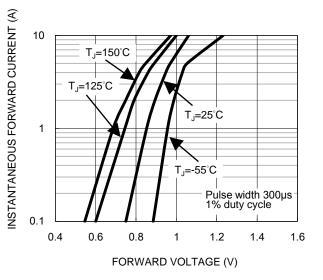
**Fig.3 Typical Reverse Characteristics** 



CAPACITANCE (pF)

#### Fig.2 Typical Junction Capacitance

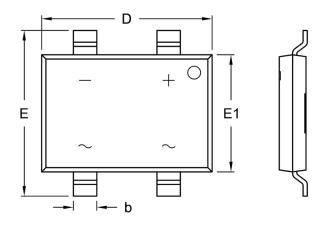
**Fig.4 Typical Forward Characteristics** 





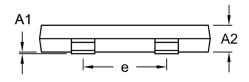


## **PACKAGE OUTLINE DIMENSIONS**

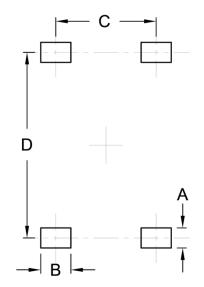


L

DIM	Unit (mm)		Unit (	(inch)
	Min	Max	Min	Max
A1	0.00	0.15	0.000	0.006
A2	1.40	1.80	0.055	0.071
b	1.30	1.50	0.051	0.059
D	10.00	10.40	0.394	0.409
E	9.70	10.10	0.382	0.398
E1	6.80	7.20	0.268	0.283
е	4.90	5.10	0.193	0.201
L	0.50	1.10	0.020	0.043



### SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
А	1.00	0.039
В	1.50	0.059
С	5.00	0.197
D	9.25	0.364





P/N = Marking Code

= Date Code YW

F = Factory Code



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